

## Product Overview

### NSS12500UW3: Low VCE(sat) Transistor, PNP, 12 V, 5.0 A

For complete documentation, see the data sheet.

Low VCE(sat) Bipolar Transistors are miniature surface mount devices featuring ultra low saturation voltage VCE(sat) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

#### Features

- High Current, Low VCEsat, ESD Robust, High Current Gain, High Cut Off Frequency, Low Profile Package, Linear Gain (Beta)

#### Benefits

- Improved Circuit Efficiency, Decreased Battery Charge Time, Reduce component count, High Frequency Switching, Smaller Portable Product, No distortion

#### Part Electrical Specifications

Product	Pricing (\$/Unit)	Compliance	Status	Polarity	Type	V <sub>CE(sat)</sub> Max (V)	I <sub>C</sub> Cont. (A)	V <sub>CEO</sub> Min (V)	V <sub>CBO</sub> (V)	V <sub>EBO</sub> (V)	V <sub>BE(sat)</sub> (V)	V <sub>BE(on)</sub> (V)	h <sub>FE</sub> Min	h <sub>FE</sub> Max	f <sub>T</sub> Min (MHz)	P <sub>TM</sub> Max (W)	Package Type
NSS12500UW3T2G	0.3237	Pb-free Halide free non AEC-Q and PPAP	Active	PNP	Low V <sub>CE(sat)</sub>	0.26	5	12	12	7	0.9	0.9	250	-	100	1.5	WDFN-3

For more information please contact your local sales support at [www.onsemi.com](http://www.onsemi.com).

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